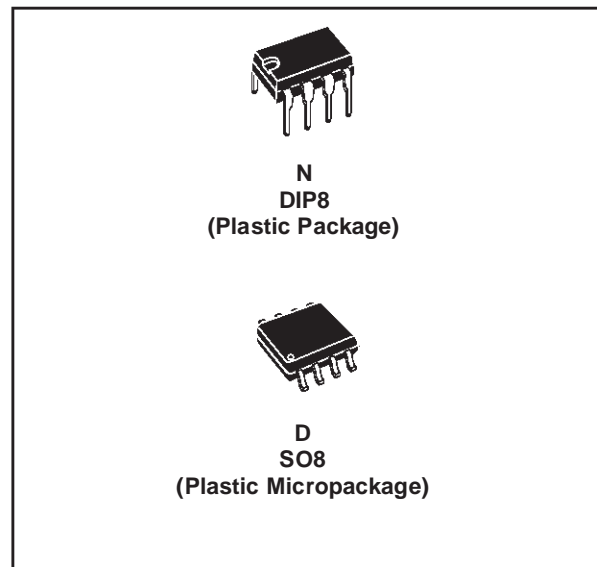




**LOW NOISE J-FET DUAL OPERATIONAL AMPLIFIERS**

- WIDE COMMON-MODE (UP TO  $V_{CC}^+$ ) AND DIFFERENTIAL VOLTAGE RANGE
- LOW INPUT BIAS AND OFFSET CURRENT
- LOW NOISE  $e_n = 15nV/\sqrt{Hz}$  (typ)
- OUTPUT SHORT-CIRCUIT PROTECTION
- HIGH INPUT IMPEDANCE J-FET INPUT STAGE
- LOW HARMONIC DISTORTION : 0.01% (typ)
- INTERNAL FREQUENCY COMPENSATION
- LATCH UP FREE OPERATION
- HIGH SLEW RATE :  $16V/\mu s$  (typ)

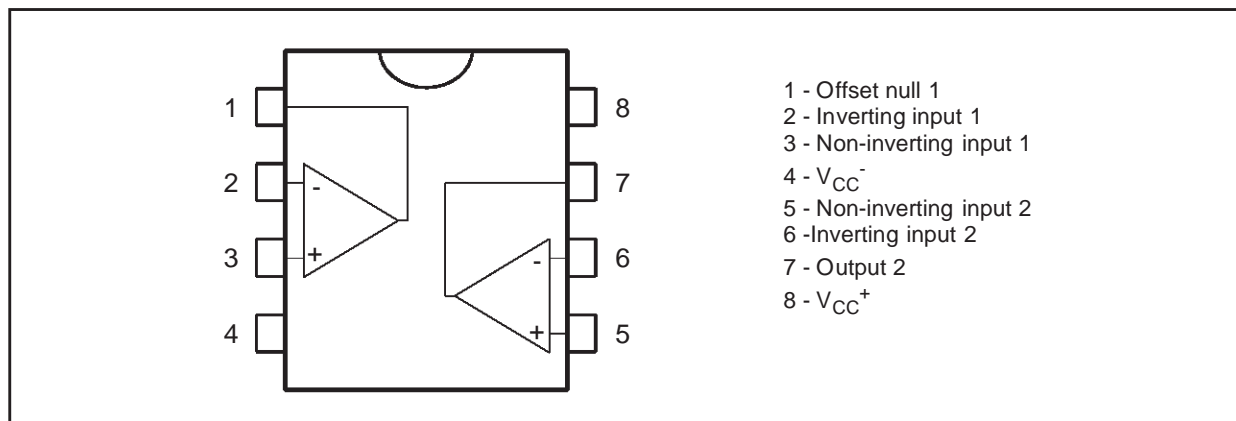


**DESCRIPTION**

The TL072, TL072A and TL072B are high speed J-FET input dual operational amplifiers incorporating well matched, high voltage J-FET and bipolar transistors in a monolithic integrated circuit.

The devices feature high slew rates, low input bias and offset current, and low offset voltage temperature coefficient.

**PIN CONNECTIONS** (top view)



**ORDER CODE**

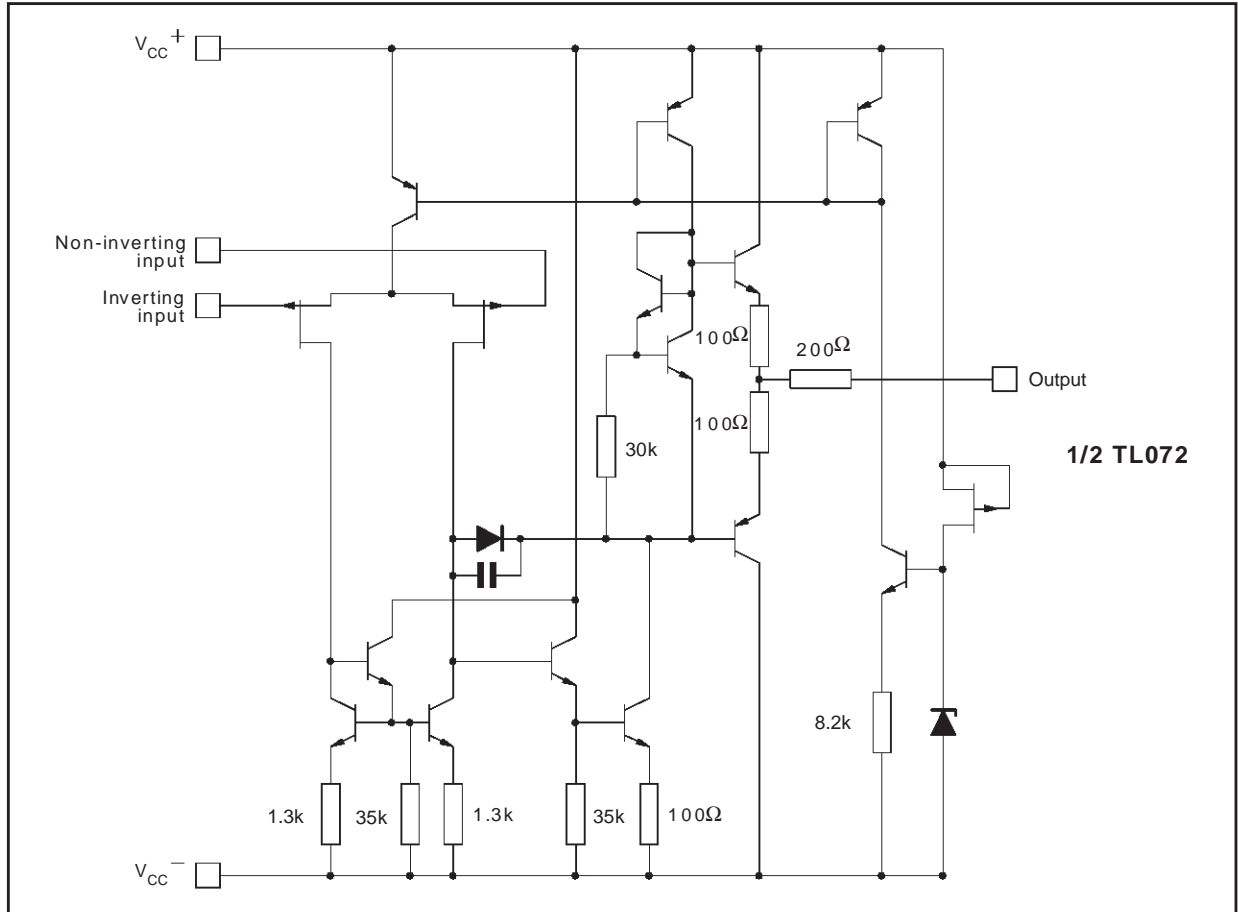
Part Number	Temperature Range	Package	
		N	D
TL072M/AM/BM	-55°C, +125°C	•	•
TL072I/AI/BI	-40°C, +105°C	•	•
TL072C/AC/BC	0°C, +70°C	•	•

**Example : TL072CN**

N = Dual in Line Package (DIP)  
 D = Small Outline Package (SO) - also available in Tape & Reel (DT)

# TL072 - TL072A - TL072B

## SCHEMATIC DIAGRAM



## ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	TL072M, AM, BM	TL072I, AI, BI	TL072C, AC, BC	Unit
$V_{CC}$	Supply voltage - note 1)		$\pm 18$		V
$V_i$	Input Voltage - note 2)		$\pm 15$		V
$V_{id}$	Differential Input Voltage - note 3)		$\pm 30$		V
$P_{tot}$	Power Dissipation		680		mW
	Output Short-circuit Duration - note 4)		Infinite		
$T_{oper}$	Operating Free-air Temperature Range	-55 to +125	-40 to +105	0 to +70	°C
$T_{stg}$	Storage Temperature Range		-65 to +150		°C

1. All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between  $V_{CC}^+$  and  $V_{CC}^-$ .
2. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.
3. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
4. The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

**ELECTRICAL CHARACTERISTICS**

V<sub>CC</sub> = ±15V, T<sub>amb</sub> = +25°C (unless otherwise specified)

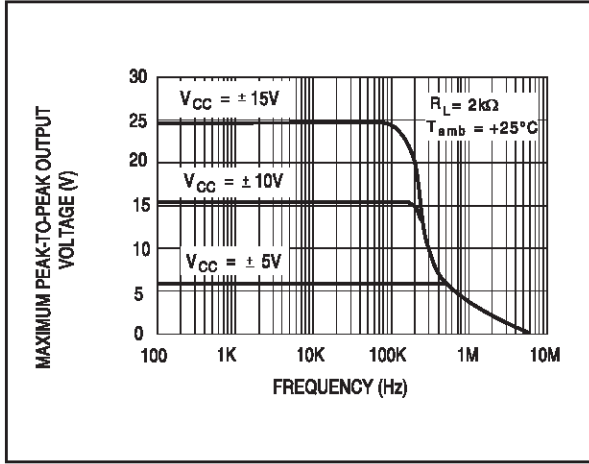
Symbol	Parameter	TL072I,M,AC,AI,AM, BC,BI,BM			TL072C			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
V <sub>io</sub>	Input Offset Voltage (R <sub>S</sub> = 50Ω) T <sub>amb</sub> = +25°C T <sub>min</sub> ≤ T <sub>amb</sub> ≤ T <sub>max</sub>		3 3 1	10 6 3 13 7 5		3 10	10 13	mV
DV <sub>io</sub>	Input Offset Voltage Drift		10			10		μV/°C
I <sub>io</sub>	Input Offset Current - note 1) T <sub>amb</sub> = +25°C T <sub>min</sub> ≤ T <sub>amb</sub> ≤ T <sub>max</sub>		5	100 4		5 100	10 10	pA nA
I <sub>ib</sub>	Input Bias Current -note 1 T <sub>amb</sub> = +25°C T <sub>min</sub> ≤ T <sub>amb</sub> ≤ T <sub>max</sub>		20	200 20		20 200	20 20	pA nA
A <sub>vd</sub>	Large Signal Voltage Gain (R <sub>L</sub> = 2kΩ, V <sub>o</sub> = ±10V) T <sub>amb</sub> = +25°C T <sub>min</sub> ≤ T <sub>amb</sub> ≤ T <sub>max</sub>	50 25	200		25 15	200		V/mV
SVR	Supply Voltage Rejection Ratio (R <sub>S</sub> = 50Ω) T <sub>amb</sub> = +25°C T <sub>min</sub> ≤ T <sub>amb</sub> ≤ T <sub>max</sub>	80 80	86		70 70	86		dB
I <sub>CC</sub>	Supply Current, no load T <sub>amb</sub> = +25°C T <sub>min</sub> ≤ T <sub>amb</sub> ≤ T <sub>max</sub>		1.4	2.5 2.5		1.4 2.5	2.5 2.5	mA
V <sub>icm</sub>	Input Common Mode Voltage Range	±11	+15 -12		±11	+15 -12		V
CMR	Common Mode Rejection Ratio (R <sub>S</sub> = 50Ω) T <sub>amb</sub> = +25°C T <sub>min</sub> ≤ T <sub>amb</sub> ≤ T <sub>max</sub>	80 80	86		70 70	86		dB
I <sub>os</sub>	Output Short-circuit Current T <sub>amb</sub> = +25°C T <sub>min</sub> ≤ T <sub>amb</sub> ≤ T <sub>max</sub>	10 10	40	60 60	10 10	40	60 60	mA
±V <sub>opp</sub>	Output Voltage Swing T <sub>amb</sub> = +25°C T <sub>min</sub> ≤ T <sub>amb</sub> ≤ T <sub>max</sub>		10 12 10 12	12 13.5		10 12 10 12	12 13.5	V
SR	Slew Rate (T <sub>amb</sub> = +25°C) V <sub>in</sub> = 10V, R <sub>L</sub> = 2kΩ, C <sub>L</sub> = 100pF, unity gain	8	16		8	16		V/μs
t <sub>r</sub>	Rise Time (T <sub>amb</sub> = +25°C) V <sub>in</sub> = 20mV, R <sub>L</sub> = 2kΩ, C <sub>L</sub> = 100pF, unity gain		0.1			0.1		μs
K <sub>ov</sub>	Overshoot (T <sub>amb</sub> = +25°C) V <sub>in</sub> = 20mV, R <sub>L</sub> = 2kΩ, C <sub>L</sub> = 100pF, unity gain		10			10		%
GBP	Gain Bandwidth Product (T <sub>amb</sub> = +25°C) V <sub>in</sub> = 10mV, R <sub>L</sub> = 2kΩ, C <sub>L</sub> = 100pF, f = 100kHz	2.5	4		2.5	4		MHz
R <sub>i</sub>	Input Resistance		10 <sup>12</sup>			10 <sup>12</sup>		Ω

## TL072 - TL072A - TL072B

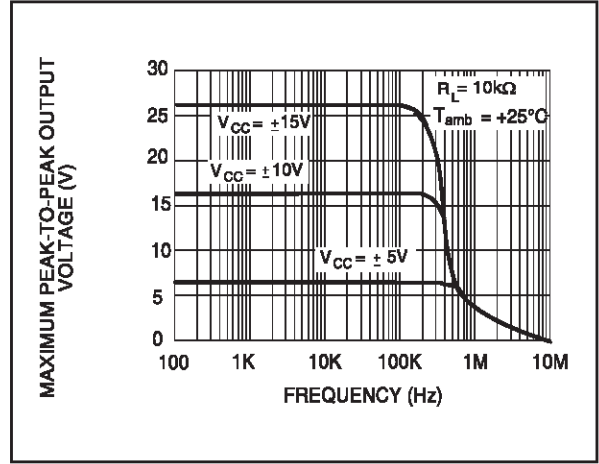
Symbol	Parameter	TL072I,M,AC,AI,AM, BC,BI,BM			TL072C			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
THD	Total Harmonic Distortion ( $T_{amb} = +25^{\circ}\text{C}$ ) $f = 1\text{kHz}$ , $R_L = 2\text{k}\Omega$ , $C_L = 100\text{pF}$ , $A_V = 20\text{dB}$ , $V_O = 2V_{pp}$		0.01			0.01		%
$e_n$	Equivalent Input Noise Voltage $R_S = 100\Omega$ , $f = 1\text{KHz}$		15			15		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
$\phi_m$	Phase Margin		45			45		degrees
$V_{o1}/V_{o2}$	Channel separation $A_V = 100$		120			120		dB

- The input bias currents are junction leakage currents which approximately double for every  $10^{\circ}\text{C}$  increase in the junction temperature.

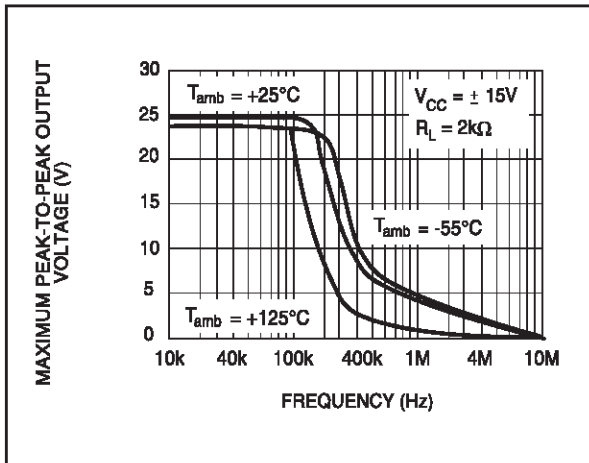
**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY**



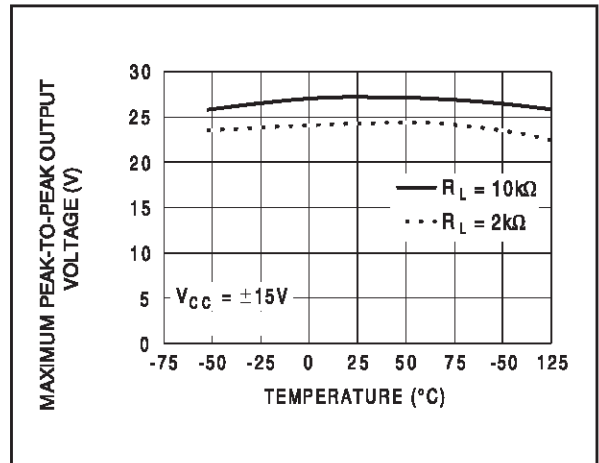
**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY**



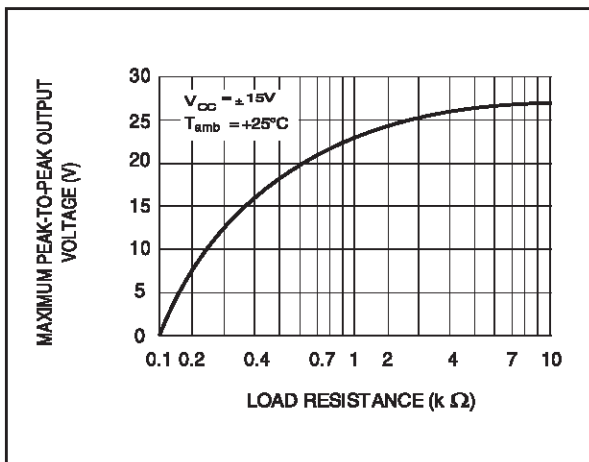
**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREQUENCY**



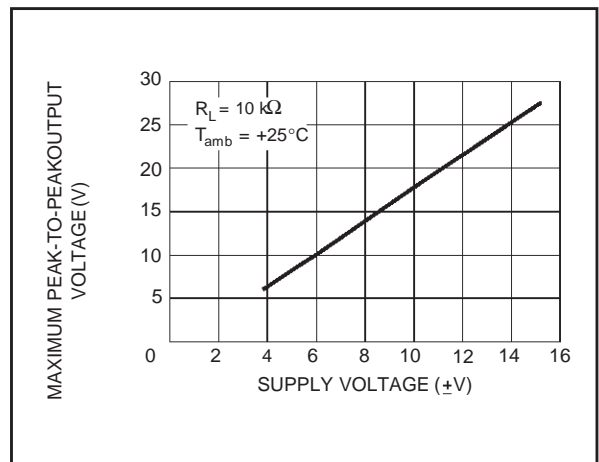
**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus FREE AIR TEMP.**



**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus LOAD RESISTANCE**

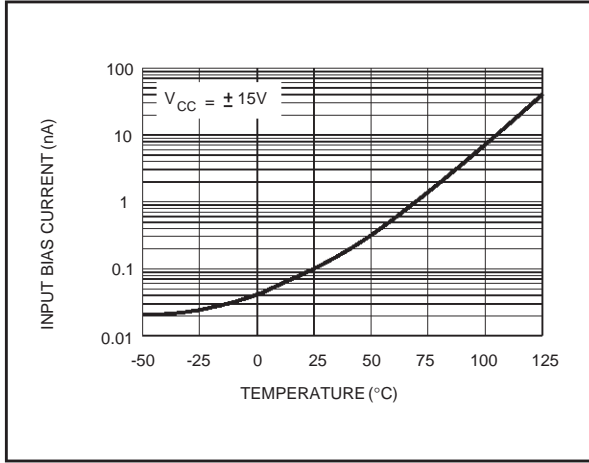


**MAXIMUM PEAK-TO-PEAK OUTPUT VOLTAGE versus SUPPLY VOLTAGE**

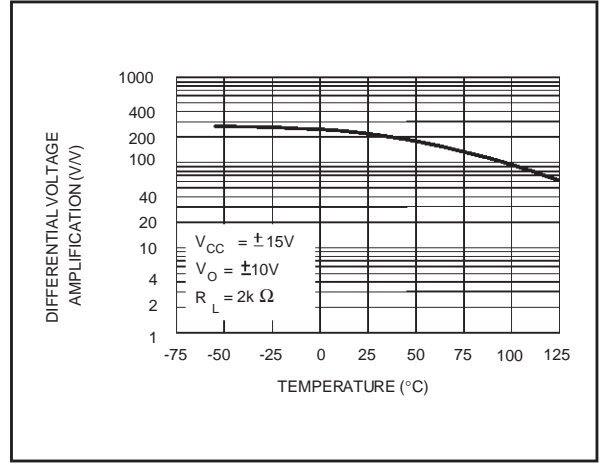


**TL072 - TL072A - TL072B**

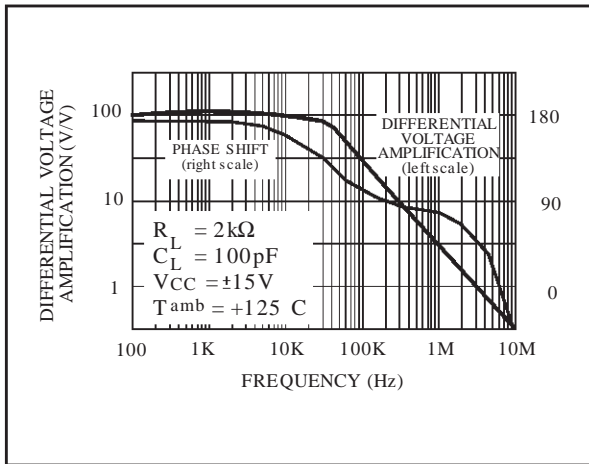
**INPUT BIAS CURRENT versus FREE AIR TEMPERATURE**



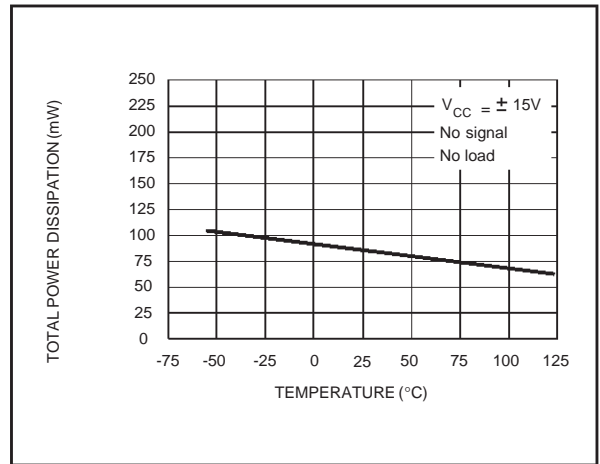
**LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION versus FREE AIR TEMP.**



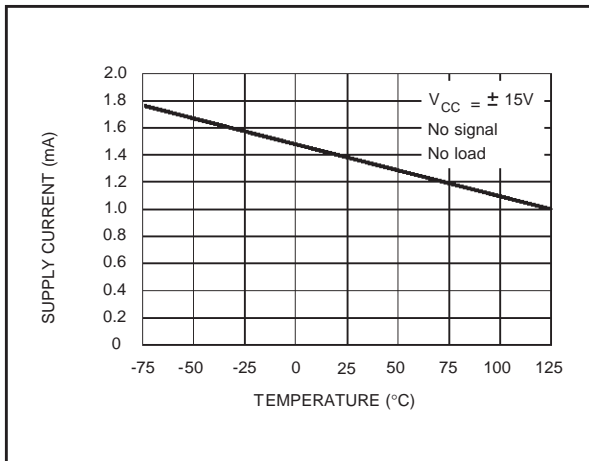
**LARGE SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE SHIFT versus FREQUENCY**



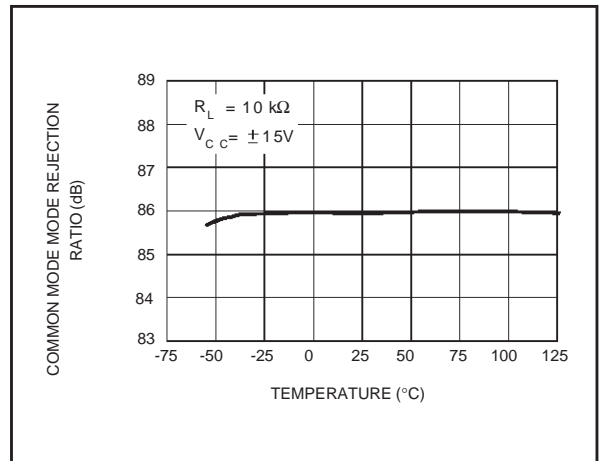
**TOTAL POWER DISSIPATION versus FREE AIR TEMPERATURE**



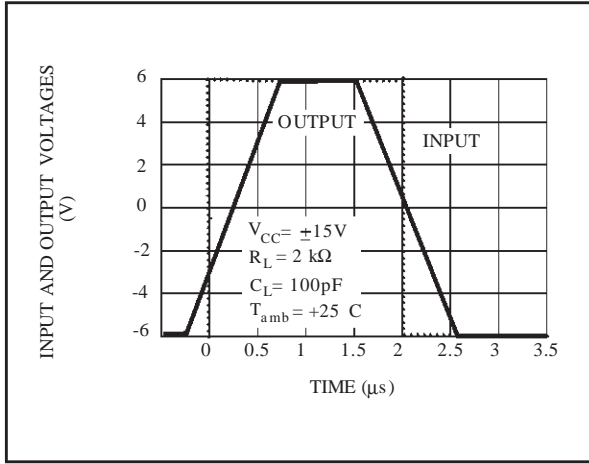
**SUPPLY CURRENT PER AMPLIFIER versus FREE AIR TEMPERATURE**



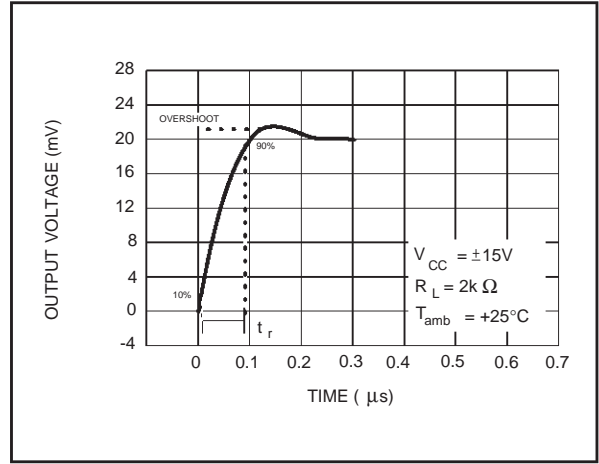
**COMMON MODE REJECTION RATIO versus FREE AIR TEMPERATURE**



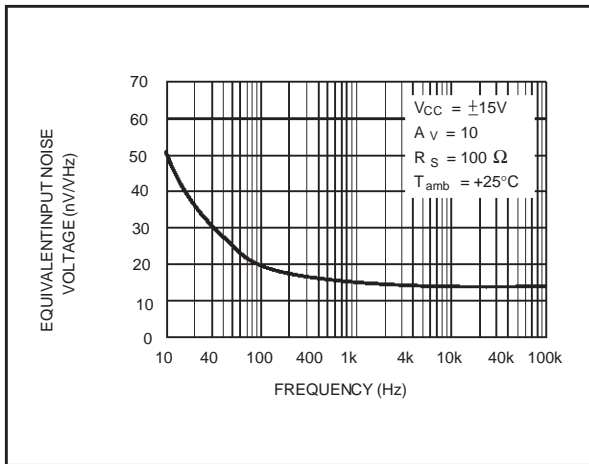
**VOLTAGE FOLLOWER LARGE SIGNAL PULSE RESPONSE**



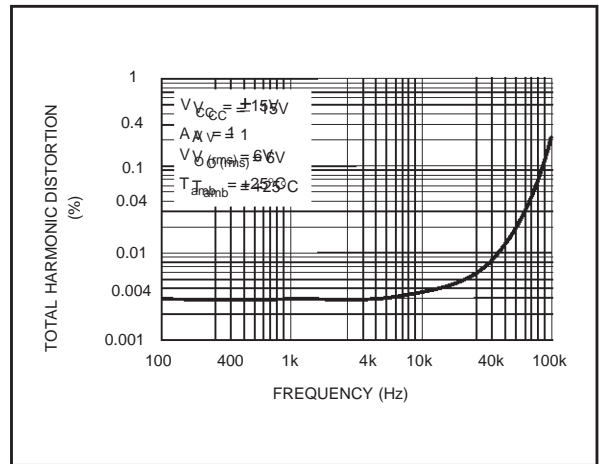
**OUTPUT VOLTAGE versus ELAPSED TIME**



**EQUIVALENT INPUT NOISE VOLTAGE versus FREQUENCY**



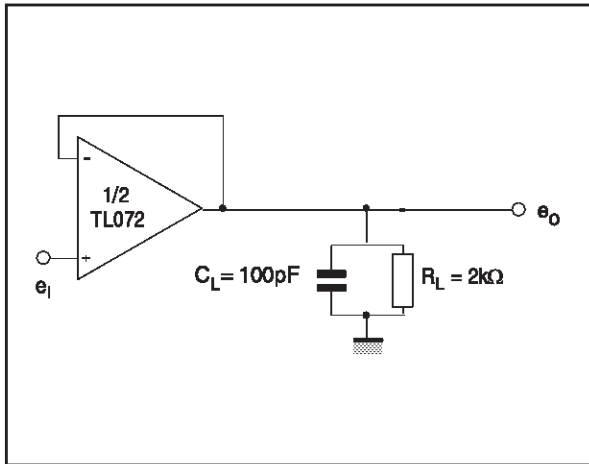
**TOTAL HARMONIC DISTORTION versus FREQUENCY**



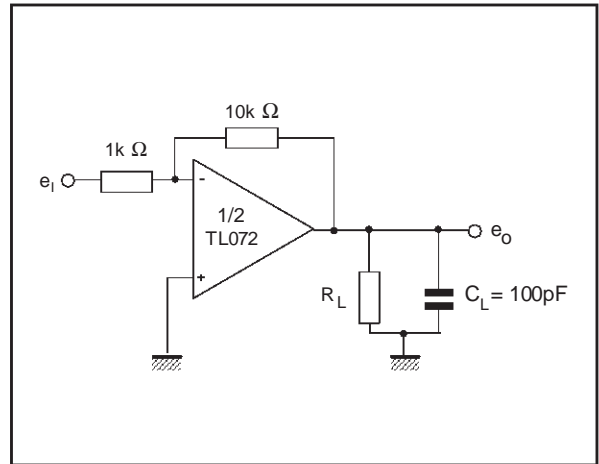
# TL072 - TL072A - TL072B

## PARAMETER MEASUREMENT INFORMATION

**Figure 1 : Voltage Follower**

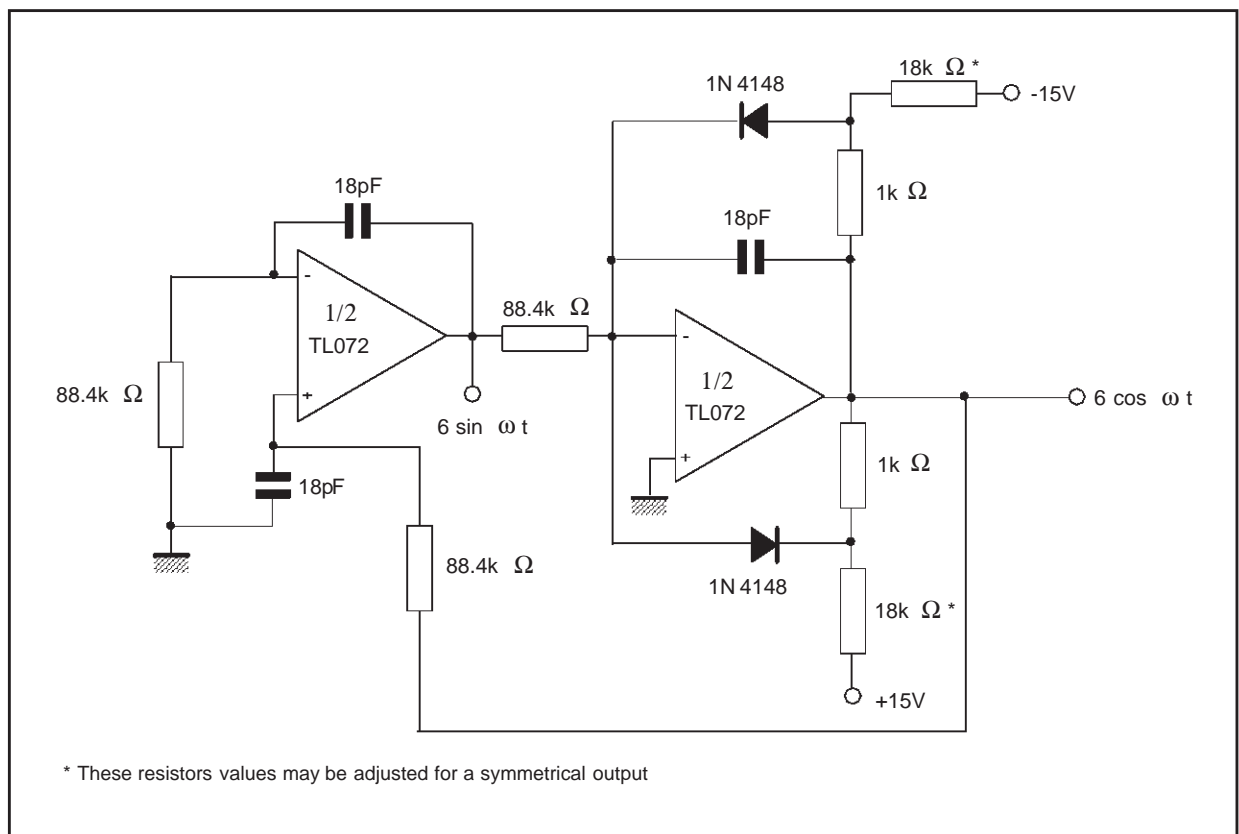


**Figure 2 : Gain-of-10 Inverting Amplifier**



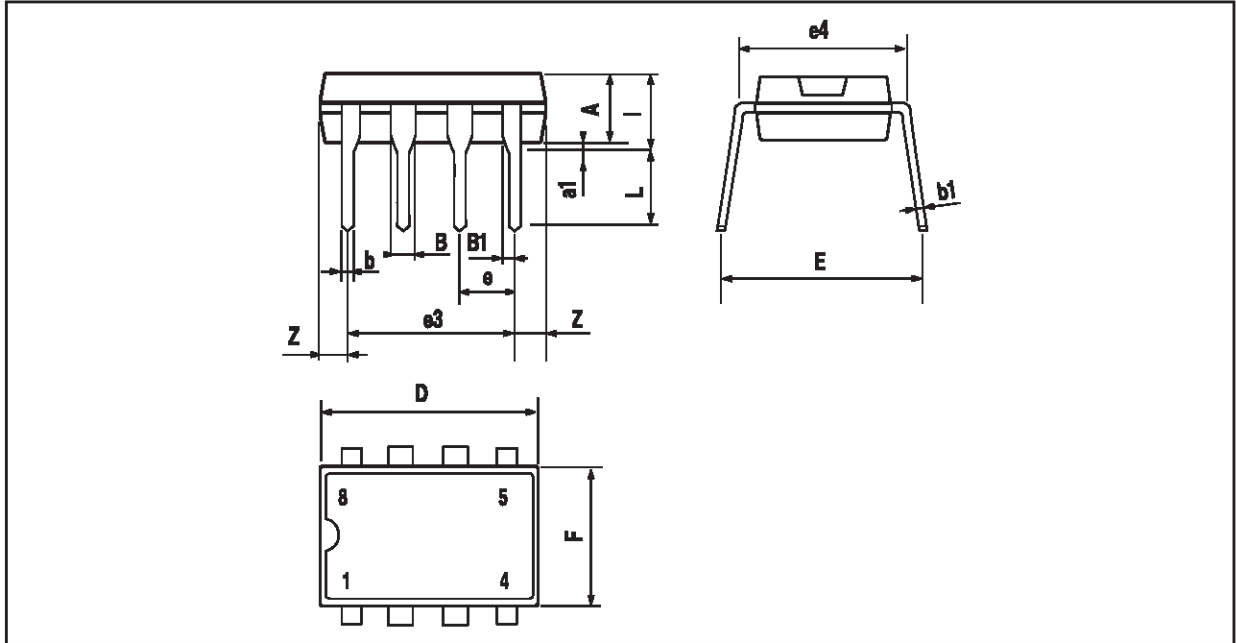
## TYPICAL APPLICATIONS

### 100KHz QUADRUPLE OSCILLATOR





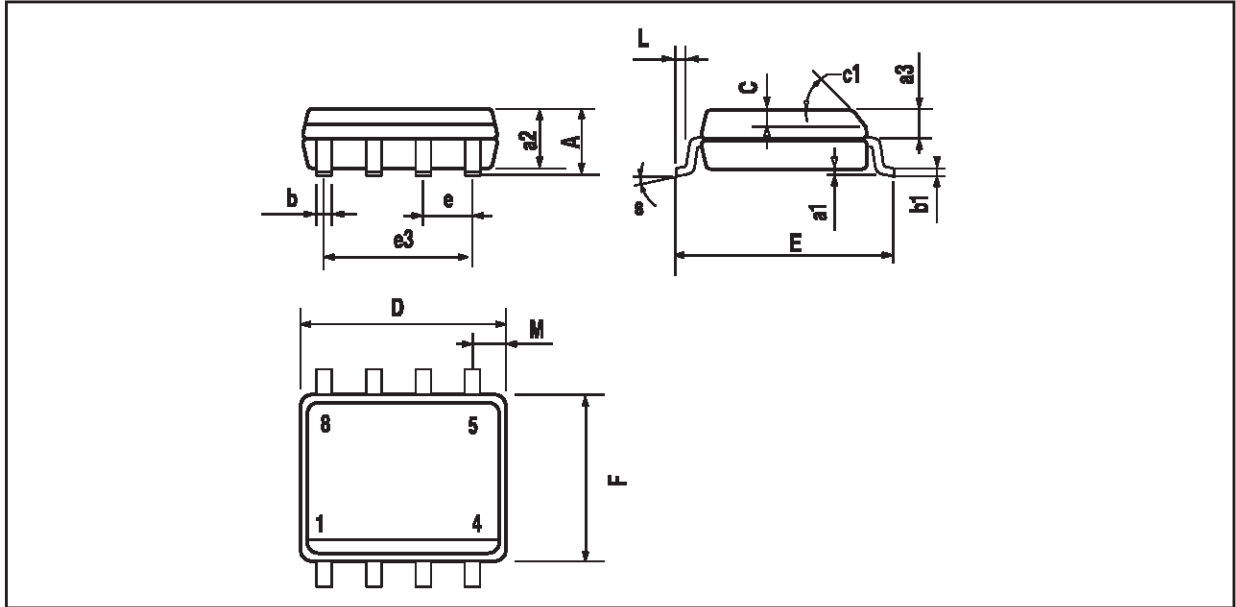
**PACKAGE MECHANICAL DATA**  
8 PINS - PLASTIC DIP



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A		3.32			0.131	
a1	0.51			0.020		
B	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
e		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0.260
i			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

## TL072 - TL072A - TL072B

### PACKAGE MECHANICAL DATA 8 PINS - PLASTIC MICROPACKAGE (SO)



Dim.	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.25	0.004		0.010
a2			1.65			0.065
a3	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b1	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.020
c1	45° (typ.)					
D	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		3.81			0.150	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
M			0.6			0.024
S	8° (max.)					

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